

Electronic structure of Yb compounds probed by hard X-ray photoemission spectroscopy

Yb compounds exhibit interesting physical properties originating from the hybridization between localized 4f electrons and itinerant conduction electrons (c-f hybridization). When the c-f hybridization is weak, the Ruderman-Kittel-Kasuya-Yosida interaction, where the 4f moments at different Yb sites interact indirectly mediated by the conduction electrons, is dominant and a magnetic order is realized at low temperatures. In contrast, when the c-f hybridization is strong, the Kondo effect becomes dominant and the 4f moments are screened with the conduction electrons, leading to a nonmagnetic ground state. The situation is summarized in the Doniach phase diagram [1]. The boundary point separating the magnetic and nonmagnetic ground state regions defines the quantum critical point (QCP). Unconventional physical phenomena such as superconductivity and a non-Fermi liquid state, where the electrical resistivity and specific heat, for example, show temperature dependences different from those in the normal metals, are observed near the QCP. In the study of 4f electron systems, one of the most important issues is to establish the electronic structure around the QCP.

YbNi₃X₉ and Yb₂Pt₆X₁₅ (X=AI, Ga) are suitable systems for investigating the change in electronic structure across the QCP. YbNi₃Al₉ exhibits magnetic order below 3.4 K, while YbNi₃Ga₉ shows no magnetic order. YbNi₃Al₉ and YbNi₃Ga₉ thus occupy the weak and strong c–f hybridization regions, respectively, across the QCP in the Doniach phase diagram, in spite of having the same crystal structure and similar conduction electronic states. Although YbNi₃X₉ and Yb₂Pt₆X₁₅ have similar crystal structures and are both located in the nonmagnetic region, magnetic susceptibility measurements indicate that $Yb_2Pt_6AI_{15}$ is closer to the QCP than $Yb_2Pt_6Ga_{15}$. Thus, $YbNi_3X_9$ and $Yb_2Pt_6X_{15}$ provide an opportunity to systematically investigate the change in electronic structure in moving from magnetic (weak c-f hybridization) to nonmagnetic (strong c-f hybridization) regions in the Doniach phase diagram across the QCP. In this study, we carried out hard X-ray photoemission spectroscopy (HAXPES) measurements at hv = 5.95 keV on YbNi₃X₉ and Yb₂Pt₆X₁₅ at SPring-8 **BL15XU** [2,3].

The Yb $3d_{5/2}$, Ni $2p_{3/2}$ (YbNi₃X₉) and Pt $4f_{7/2}$ (Yb₂Pt₆X₁₅) and valence-band HAXPES spectra of YbNi₃X₉ and Yb₂Pt₆X₁₅ measured at 20 K showed similar X-dependences (Fig. 1) as follows. The Yb $3d_{5/2}$ spectrum is split into the Yb²⁺ ($4f^{14}$) and Yb³⁺ ($4f^{13}$) parts. The Yb²⁺ peak is very tiny for X = AI and is enhanced for X = Ga, indicating that the Yb valence is shifted from almost trivalent toward divalent states. The Ni $2p_{3/2}$ and Pt $4f_{7/2}$ peaks for X = Ga are located at a lower binding energy (E_B) than those for X = AI. The same energy shift is observed for the Ni 3*d* and Pt 5*d* structures in the valence-band spectra. In contrast, the opposite energy shift is observed in the Yb³⁺ 4f multiplet.

The similar X-dependent spectra of $YbNi_3X_9$ and $Yb_2Pt_6X_{15}$ suggest some systematic changes in electronic structure in moving from weak (X=AI) to strong (X=Ga) c-f hybridization regions in the Doniach phase diagram. A simple electronic model (Fig. 2) qualitatively explains these experimental results. The



Fig. 1. (a) Yb $3d_{5/2}$, (b) Ni $2p_{3/2}$ and (c) valence-band HAXPES spectra of YbNi₃X₉ and (d) Yb $3d_{5/2}$, (e) Pt $4f_{7/2}$ and (f) valence-band HAXPES spectra of Yb₂Pt₆X₁₅ measured at 20 K. The spectra at h_V = 182 eV obtained at BL-7 of HiSOR to enhance the Yb³⁺ 4f peak are also presented in (f).





Yb 4f and conduction-band densities of states (DOS) are drawn at the left and right sides of the energy axis, respectively. The Yb3+ 4f level is split into the occupied and unoccupied levels at the energy distance of the Coulomb interaction energy between the 4f electrons (U_{ff}) . The 4f hole level for X = Al is located far above the Fermi energy (E_F) , and the Yb valence is close to 3. On going from X = AI to X = Ga, the 4f hole level becomes closer to $E_{\rm F}$, and as a result, the occupied 4f level is shifted to higher $E_{\rm B}$ side, as observed in the experiments. The conduction electrons are easily transferred to the 4*f* hole just above $E_{\rm F}$, and some Yb³⁺ ions change to Yb²⁺ ions and the Yb²⁺ $4f_{7/2}$ peak appears just below $E_{\rm F}$. With the transfer of conduction electrons, $E_{\rm F}$ shifts to a smaller value in the conduction-band DOS. This $E_{\rm F}$ shift leads to the Ni $2p_{3/2}$ and Pt $4f_{7/2}$ shifts to lower $E_{\rm B}$. Thus, the X-dependent HAXPES spectra of YbNi₃X₉ and Yb₂Pt₆X₁₅ are both understood in terms of the simple electronic model (Fig. 2).

Recently, a resonant HAXPES (rHAXPES) technique has been developed at SPring-8 **BL09XU** as a Partner User Proposal (PI: Prof. K. Mimura, Osaka Prefectural University). The Yb 3*d*_{5/2} HAXPES spectra

(Figs. 1(a) and 1(d)) were obtained at a fixed photon energy. When an incident photon energy is tuned at the Yb L₃ edge (8.94 keV), a resonant behavior in the Yb²⁺ and Yb³⁺ peaks is expected. The detailed analysis of the resonant behavior provides the Coulomb interaction energy between the localized 4f and itinerant 5*d* electrons (U_{fd}), which is related to the Yb valence. Here, we present rHAXPES results for YbInCu₄ [4] with a valence transition at $T_V = 42$ K, where the Yb valence abruptly changes from 2.90 to 2.74 on cooling. The present results obtained at BL09XU are first reported for Yb L_3 rHAXPES. Figure 3(a) shows the Yb $3d_{5/2}$ rHAXPES spectra measured at 20 K with h_V varied from 8915 to 8965 eV. Clear resonant enhancement is successfully detected both for the Yb2+ and Yb3+ peaks around the Yb L_3 edge. Figure 3(b) shows the Yb²⁺ and Yb3+ peak intensities as a function of hv, called constant initial state (CIS) spectra. The Yb2+ and Yb3+ CIS spectra exhibit similar behaviors. As hv increases from 8915 eV, the intensity gradually decreases. After reaching a minimum, the intensity rapidly attains a maximum and then again decreases. The CIS spectra are well fitted with the Fano profile given by $(E+q)^{2}/(E^{2}+1)$ with $E = (hv - E_{0})/\Gamma$, where E_{0} , Γ and a are the resonant photon energy, the half-width of the resonance and the asymmetry parameter, respectively.

The Yb²⁺ CIS spectrum is shifted to a lower photon energy than the Yb³⁺ CIS spectrum. The amount of energy shift provides information on U_{fd} , which plays an important role in the valence transition. In the present experiment, no clear change between the CIS spectra measured at 20 and 70 K across the valence transition was detected. To enable further discussion, a theoretical calculation based on the single impurity Anderson model is in progress.



Fig. 3. (a) hv dependence of Yb $3d_{5/2}$ rHAXPES spectra around the Yb L_3 edge of YbInCu₄ measured at 20 K. (b) CIS spectra of Yb³⁺ (squares, upper panel) and Yb²⁺ (circles, lower panel) components in the Yb $3d_{5/2}$ rHAXPES spectra in (a). The Fano profiles are shown by line curves.

Hitoshi Sato

Hiroshima Synchrotron Radiation Center, Hiroshima University

Email: jinjin@hioshima-u.ac.jp

References

 S. Doniach: Physica B+C 91 (1977) 231.
Y. Utsumi et al.: Phys. Rev. B 86 (2012) 115114.
A. Rousuli et al.: Phys. Rev. B 96 (2017) 045117.
K. Maeda, H. Sato, Y. Akedo, T. Kawabata, K. Abe, R. Shimokasa, A. Yasui, M. Mizumaki, N. Kawamura, E. Ikenaga, S. Tsutsui, K. Matsumoto, K. Hiraoka and K. Mimura: JPS Conf. Proc. 30 (2020) 011137.